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MOSFET - N-Channel Shielded Gate PowerTrench[®]

150 V, 7.3 mΩ, 101 A

NTB7D3N15MC

Features

- Shielded Gate MOSFET Technology
- Max $R_{DS(on)} = 7.3 \text{ m}\Omega$ at $V_{GS} = 10 \text{ V}$, $I_D = 62 \text{ A}$
- 50% Lower Qrr than other MOSFET Suppliers
- Lowers Switching Noise/EMI
- 100% UIL Tested
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- Motor Drives and Uninterruptible Power Supplies
- Micro Solar Inverter

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

r	,				
Parameter		Symbol	Value	Unit	
Drain-to-Source Voltage		V _{DSS}	150	V	
Gate-to-Source Voltage		V _{GS}	±20	V	
$\begin{array}{l} \text{Continuous Drain} \\ \text{Current } R_{\theta JC} \\ \text{(Note 2)} \end{array}$	Steady State	T _C = 25°C	Ι _D	101	A
Power Dissipation $R_{\theta JC}$ (Note 2)	State		P _D	166	W
Continuous Drain Current $R_{\theta JA}$ (Notes 1, 2)	Steady State	T _A = 25°C	Ι _D	15.2	A
Power Dissipation $R_{\theta JA}$ (Notes 1, 2)			P _D	3.75	W
Pulsed Drain Current	$T_{C} = 25^{\circ}C, t_{p} = 100 \ \mu s$		I _{DM}	488	А
Operating Junction and Storage Temperature Range		T _J , T _{stg}	–55 to +175	°C	
Single Pulse Drain-to-Source Avalanche Energy ($I_L = 20 A_{pk}$, L = 3 mH)		E _{AS}	600	mJ	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		ΤL	260	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using a 1 in², 2 oz. Cu pad.

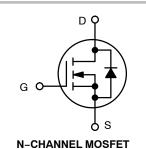
The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

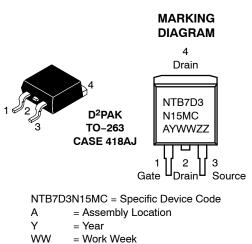


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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
150 V	7.3 mΩ @ 10 V	101 A





ZZ = Lot Traceability

ORDERING INFORMATION

Device	Package	Shipping [†]		
NTB7D3N15MC	D ² PAK (Pb–Free)	800 / Tape & Reel		

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Downloaded from Arrow.com.

THERMAL RESISTANCE MAXIMUM RATINGS

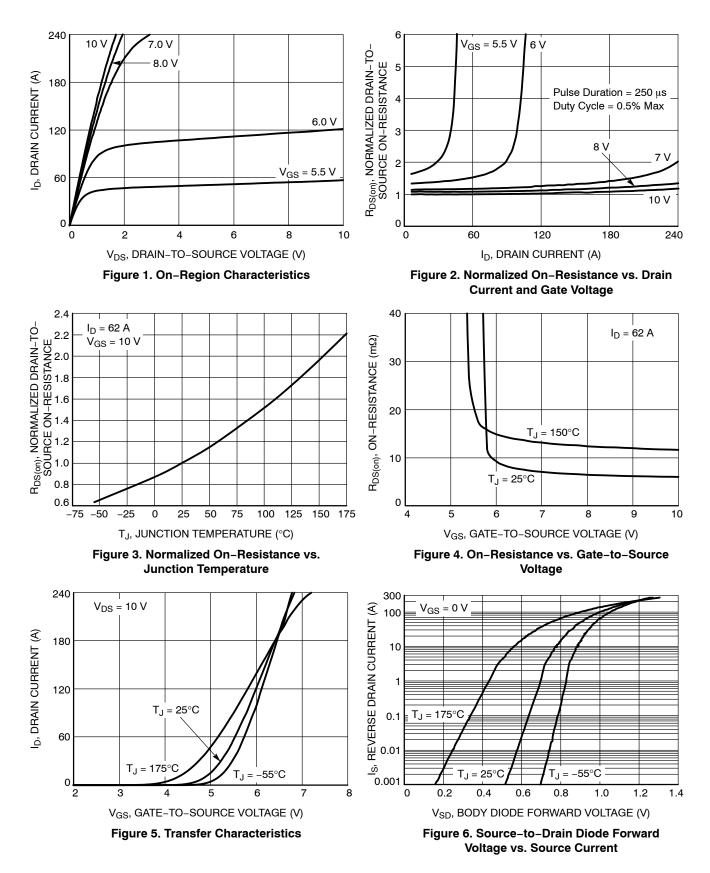
Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State (Note 2)	$R_{ ext{ heta}JC}$	0.9	°C/W
Junction-to-Ambient - Steady State (Notes 1, 2)	$R_{ hetaJA}$	40	

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

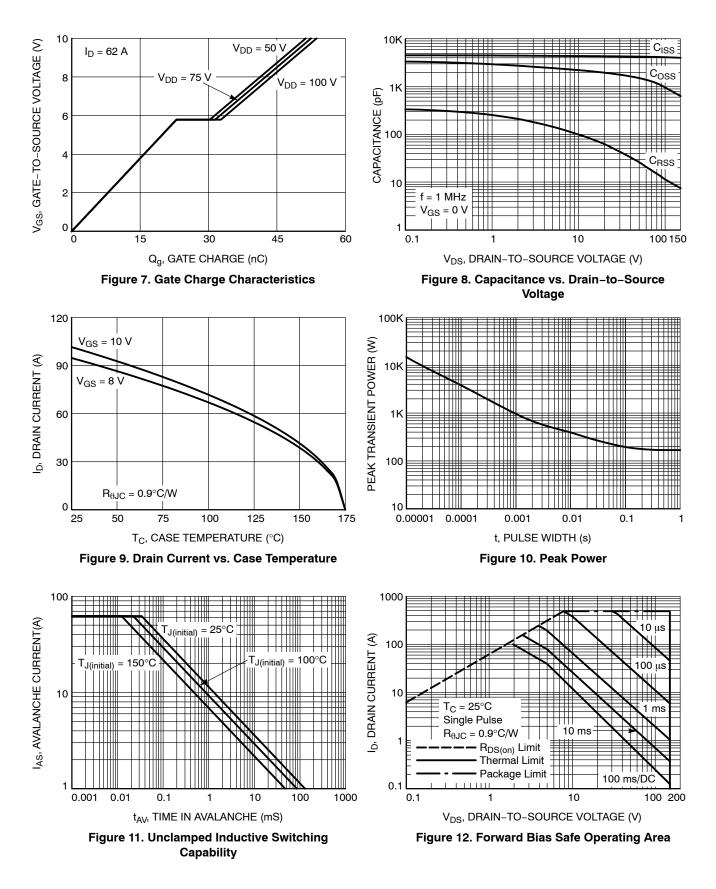
Parameter	Symbol	Test Condition	n	Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 250 μ A		150			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J	$I_D = 250 \ \mu\text{A}$, ref to 25°C			71		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = 120 V	T _J = 25°C			1.0	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±20 V				±100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 34$	12 μA	2.5		4.5	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J	$I_D = 342 \ \mu A$, ref to	25°C		-7.3		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V_{GS} = 10 V, I _D = 62 A V_{GS} = 8 V, I _D = 31 A			6.0	7.3	mΩ
					6.5	8.4	
Forward Transconductance	9 _{FS}	V _{DS} = 10 V, I _D = 62 A			119		S
CHARGES, CAPACITANCES & GATE RESIS	TANCE						
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 75 V			4250		pF
Output Capacitance	C _{OSS}				1250		
Reverse Transfer Capacitance	C _{RSS}				15		
Gate-Resistance	R _G				0.8	1.6	Ω
Total Gate Charge	Q _{G(TOT)}				53		-0
Threshold Gate Charge	Q _{G(TH)}		ſ		14		
Gate-to-Source Charge	Q _{GS}	V_{GS} = 10 V, V_{DS} = 75 V; I_{D} = 62 A			23		nC
Gate-to-Drain Charge	Q _{GD}				8.5		
Plateau Voltage	V _{GP}				5.8		V
Output Charge	Q _{OSS}	V _{DD} = 75 V, V _{GS} = 0 V			133		nC
SWITCHING CHARACTERISTICS (Note 3)							
Turn-On Delay Time	t _{d(ON)}				27		
Rise Time	t _r	V_{GS} = 10 V, V_{DD} = 75 V, I_{D} = 62 A, R_{G} = 4.7 Ω			8.5		ns
Turn-Off Delay Time	t _{d(OFF)}				33		
Fall Time	t _f				5.8		
DRAIN-SOURCE DIODE CHARACTERISTIC	s					-	
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V, I _S = 62 A	T _J = 25°C		0.93	1.2	V
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, V _{DD} = 75 V dI _S /dt = 300 A/μs, I _S = 62 A			55		ns
Reverse Recovery Charge	Q _{RR}				247		nC
Reverse Recovery Time	t _{RR}	V_{GS} = 0 V, V_{DD} = 75 V dI _S /dt = 1000 A/µs, I _S = 62 A			50		ns
Reverse Recovery Charge	Q _{RR}				720		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.3. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

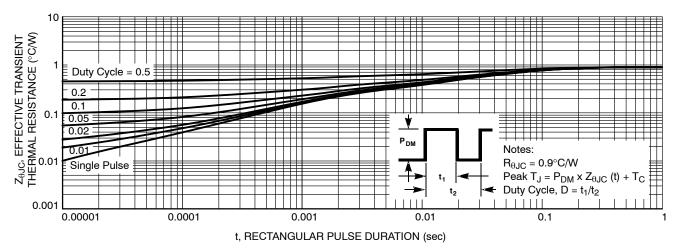
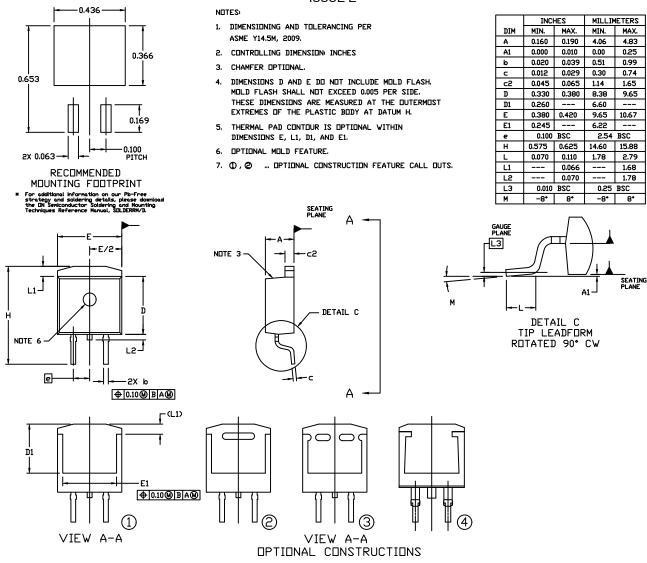


Figure 13. Transient Thermal Impedance

PACKAGE DIMENSIONS

D²PAK-3 (TO-263, 3-LEAD) CASE 418AJ

ISSUE E



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